

High Speed CMOS Logic Presettable Synchronous 4-Bit Up/Down Counters

August 1997

Features

- Synchronous Counting and Asynchronous Loading
- Two Outputs For n-bit Cascading
- Look-Ahead Carry For High Speed Counting
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: $N_{IL} = 30\%$, $N_{IH} = 30\%$ of V_{CC} at $V_{CC} = 5V$
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, $V_{IL} = 0.8V$ (Max), $V_{IH} = 2V$ (Min)
 - CMOS Input Compatibility, $I_1 \leq 1\mu A$ at V_{OL} , V_{OH}

Description

The Harris CD74HC191, and CD74HCT191 are asynchronously presettable BCD Decade and Binary Up/Down synchronous counters, respectively.

Presetting the counter to the number on preset data inputs (P_0 - P_3) is accomplished by a Low asynchronous parallel load input (PL). Counting occurs when PL is high, Count Enable (\overline{CE}) is low, and the Up/Down ($\overline{U/D}$) is either low for up-counting or high for down-counting. The counter is incremented or decremented synchronously with the low-to-high transition of the clock (Figure 4).

When an overflow or underflow of the counter occurs, the Terminal Count output (TC), which is low during counting, goes high and remains high for one clock cycle. This output can be used for look-ahead carry in high speed cascading. The TC output also initiates the Ripple Clock. (RC) output which, normally high, goes low and remains low for the low level portion of the clock pulse. These counters can be cascaded using the Ripple Clock output (Figure 5).

If a decade counter is preset to an illegal state or assumes an illegal state when power is applied, it will return to the normal sequence in one or two counts as shown in state diagrams.

Ordering Information

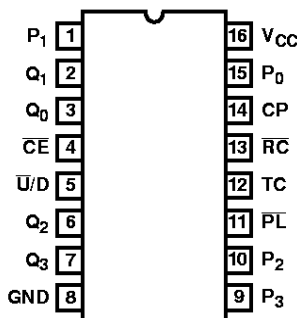
PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD74HC191E	-55 to 125	16 Ld PDIP	E16.3
CD74HCT191E	-55 to 125	16 Ld PDIP	E16.3
CD74HC191M	-55 to 125	16 Ld SOIC	M16.15
CD74HCT191M	-55 to 125	16 Ld SOIC	M16.15
CD74HC191W	-55 to 125	Wafer	

NOTE:

1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
2. Die for this part number is available which meets all electrical specifications. Please contact your local sales office or Harris customer service for ordering information.

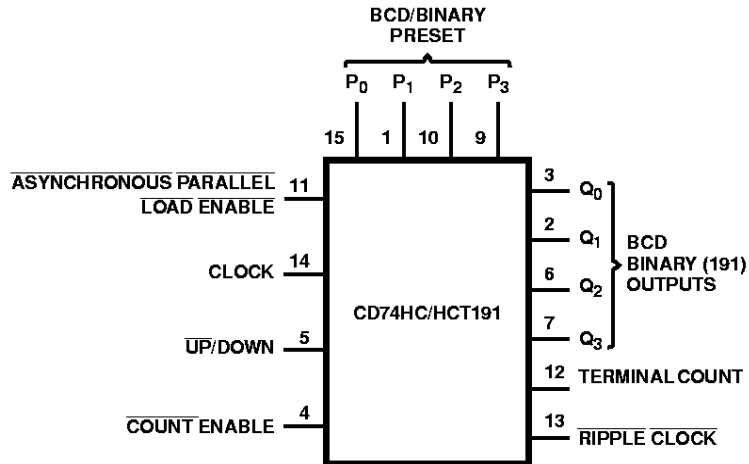
Pinout

CD74HC191, CD74HCT191
(PDIP, SOIC)
TOP VIEW



CD74HC191, CD74HCT191

Functional Diagram



TRUTH TABLE

INPUTS				FUNCTION
PL	CE	U/D	CP	
H	L	L	↑	Count Up
H	L	H	↑	Count Down
L	X	X	X	Asynchronous Preset
H	H	X	X	No Change

NOTES:

3. H = High Voltage Level, L = Low Voltage Level, X = Don't Care,
 ↑ = Transition from Low to High Level
4. U/D or CE should be changed only when clock is high.

CD74HC191, CD74HCT191

Absolute Maximum Ratings

DC Supply Voltage, V_{CC}	-0.5V to 7V
DC Input Diode Current, I_{IK}	
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$	$\pm 20mA$
DC Output Diode Current, I_{OK}	
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	$\pm 20mA$
DC Output Source or Sink Current per Output Pin, I_O	
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$	$\pm 25mA$
DC V_{CC} or Ground Current, I_{CC} or I_{GND}	$\pm 50mA$

Thermal Information

Thermal Resistance (Typical, Note 5)	θ_{JA} ($^{\circ}C/W$)
PDIP Package	90
SOIC Package	185
Maximum Junction Temperature	$150^{\circ}C$
Maximum Storage Temperature Range	$-65^{\circ}C$ to $150^{\circ}C$
Maximum Lead Temperature (Soldering 10s)	$300^{\circ}C$
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T_A)	$-55^{\circ}C$ to $125^{\circ}C$
Supply Voltage Range, V_{CC}	
HC Types	2V to 6V
HCT Types	4.5V to 5.5V
DC Input or Output Voltage, V_I , V_O	0V to V_{CC}
Input Rise and Fall Time	
2V	1000ns (Max)
4.5V	500ns (Max)
6V	400ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

- θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS		V_{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V_I (V)	I_O (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES												
High Level Input Voltage	V_{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input Voltage	V_{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output Voltage CMOS Loads	V_{OH}	V_{IH} or V_{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
High Level Output Voltage TTL Loads	V_{OH}	V_{IH} or V_{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Low Level Output Voltage CMOS Loads	V_{OL}	V_{IH} or V_{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
0.02			4.5	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output Voltage TTL Loads	V_{OL}	V_{IH} or V_{IL}	4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I_I	V_{CC} or GND	-	6	-	-	± 0.1	-	± 1	-	± 1	μA
Quiescent Device Current	I_{CC}	V_{CC} or GND	0	6	-	-	8	-	80	-	160	μA

CD74HC191, CD74HCT191

DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V _I (V)	I _O (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I _I	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	I _{CC}	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load (Note 6)	ΔI _{CC}	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

NOTE:

6. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
P0-P3	0.4
CP	1.5
PL	1.5
U/D	1.2
CE	1.5

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g. 360μA max at 25°C.

Prerequisite For Switching Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	25°C			-40°C to 85°C		-55°C to 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES											
Setup Time	t _{SU}	-	2	60	-	-	75	-	90	-	ns
P _n to PL, CE to CP			4.5	12	-	-	15	-	18	-	ns
			6	10	-	-	13	-	15	-	ns

CD74HC191, CD74HCT191

Prerequisite For Switching Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	25°C			-40°C to 85°C		-55°C to 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
\overline{U}/D to CP	t _{SU}	-	2	90	-	-	115	-	135	-	ns
			4.5	18	-	-	23	-	27	-	ns
			6	15	-	-	20	-	23	-	ns
Hold Time P _n to \overline{P} L, \overline{C} E to CP <hr/> \overline{U}/D to CP	t _H	-	2	2	-	-	2	-	2	-	ns
			4.5	2	-	-	2	-	2	-	ns
			6	2	-	-	2	-	2	-	ns
			2	0	-	-	0	-	0	-	ns
			4.5	0	-	-	0	-	0	-	ns
			6	0	-	-	0	-	0	-	ns
Maximum Frequency (Note 7)	f _{MAX}	-	2	6	-	-	5	-	4	-	MHz
			4.5	30	-	-	25	-	20	-	MHz
			6	35	-	-	29	-	23	-	MHz
Recovery Time	t _{REC}	-	2	60	-	-	75	-	90	-	ns
			4.5	12	-	-	15	-	18	-	ns
			6	10	-	-	13	-	15	-	ns
CP Pulse Width	t _W	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
\overline{P} L Pulse Width	t _W	-	2	100	-	-	125	-	150	-	ns
			4.5	20	-	-	25	-	30	-	ns
			6	17	-	-	21	-	26	-	ns

HCT TYPES

Setup Time P _n to \overline{P} L, \overline{C} E to CP <hr/> \overline{U}/D to CP	t _{SU}	-	4.5	12	-	-	15	-	18	-	ns
			4.5	18	-	-	23	-	27	-	ns
Hold Time P _n to \overline{P} L, \overline{C} E to CP <hr/> \overline{U}/D to CP	t _H	-	4.5	2	-	-	2	-	2	-	ns
			4.5	0	-	-	0	-	0	-	ns
Maximum Frequency (Note 7)	f _{MAX}	-	4.5	30	-	-	25	-	20	-	MHz
Recovery Time	t _{REC}	-	4.5	12	-	-	15	-	18	-	ns
CP Pulse Width	t _W	-	4.5	16	-	-	20	-	24	-	ns
\overline{P} L Pulse Width	t _W	-	4.5	20	-	-	25	-	30	-	ns

Switching Specifications Input t_r, t_f = 6ns

PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	25°C			-40°C to 85°C		-55°C to 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES											
Propagation Delay P _n to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	195	-	245	-	295	ns
		C _L = 50pF	4.5	-	-	39	-	49	-	59	ns
		C _L = 15pF	5	-	16	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	33	-	42	-	50	ns

CD74HC191, CD74HCT191

Switching Specifications Input $t_r, t_f = 6\text{ns}$ (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	25°C			-40°C to 85°C		-55°C to 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
P _n to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
		C _L = 50pF	4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
CP to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	170	-	215	-	255	ns
		C _L = 50pF	4.5	-	-	34	-	43	-	51	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	29	-	37	-	43	ns
CP to \overline{RC}	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	125	-	155	-	190	ns
		C _L = 50pF	4.5	-	-	25	-	31	-	38	ns
		C _L = 15pF	5	-	10	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	21	-	26	-	32	ns
CP to TC	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	210	-	265	-	315	ns
		C _L = 50pF	4.5	-	-	42	-	53	-	63	ns
		C _L = 15pF	5	-	18	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	36	-	45	-	54	ns
$\overline{U/D}$ to \overline{RC}	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	150	-	190	-	225	ns
		C _L = 50pF	4.5	-	-	30	-	38	-	45	ns
		C _L = 15pF	5	-	12	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	26	-	33	-	38	ns
$\overline{U/D}$ to TC	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	165	-	205	-	250	ns
		C _L = 50pF	4.5	-	-	33	-	41	-	50	ns
		C _L = 15pF	5	-	13	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	28	-	35	-	43	ns
\overline{CE} to \overline{RC}	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	125	-	155	-	190	ns
		C _L = 50pF	4.5	-	-	25	-	31	-	38	ns
		C _L = 15pF	5	-	10	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	21	-	26	-	32	ns
Output Transition Time Q _n , TC, \overline{RC}	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _{IN}	C _L = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance	C _{PD}	-	-	-	55	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay PL to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	40	-	50	-	60	ns
		C _L = 15pF	5	-	17	-	-	-	-	-	ns
P _n to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	38	-	48	-	57	ns
		C _L = 15p	5	-	16	-	-	-	-	-	ns
CP to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	35	-	44	-	53	ns
		C _L = 15p	5	-	14	-	-	-	-	-	ns

CD74HC191, CD74HCT191

Switching Specifications Input $t_r, t_f = 6\text{ns}$ (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	V_{CC} (V)	25°C			-40°C to 85°C		-55°C to 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
CP to \overline{RC}	t_{PLH}, t_{PHL}	$C_L = 50\text{pF}$	4.5	-	-	27	-	34	-	41	ns
		$C_L = 15\text{p}$	5	-	11	-	-	-	-	-	ns
CP to TC	t_{PLH}, t_{PHL}	$C_L = 50\text{pF}$	4.5	-	-	42	-	53	-	63	ns
		$C_L = 15\text{p}$	5	-	18	-	-	-	-	-	ns
$\overline{U/D}$ to \overline{RC}	t_{PLH}, t_{PHL}	$C_L = 50\text{pF}$	4.5	-	-	30	-	38	-	45	ns
		$C_L = 15\text{p}$	5	-	12	-	-	-	-	-	ns
$\overline{U/D}$ to TC	t_{PLH}, t_{PHL}	$C_L = 50\text{pF}$	4.5	-	-	38	-	48	-	57	ns
		$C_L = 15\text{p}$	5	-	16	-	-	-	-	-	ns
\overline{CE} to \overline{RC}	t_{PLH}, t_{PHL}	$C_L = 50\text{pF}$	4.5	-	-	27	-	34	-	41	ns
		$C_L = 15\text{p}$	5	-	11	-	-	-	-	-	ns
Output Transition Time Q_n, TC, \overline{RC}	t_{TLH}, t_{THL}	$C_L = 50\text{pF}$	4.5	-	-	15	-	19	-	22	pF
Input Capacitance	C_{IN}	$C_L = 50\text{pF}$	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 8, 9)	C_{PD}	191	-	-	68	-	-	-	-	-	pF

NOTES:

7. Applies to noncascaded operation only. With cascaded counter clock-to-terminal propagation delays, count enable (\overline{CE})-to-clock setup times, and count enable (\overline{CE})-to-clock hold times determine max. clock frequency. For example, with these HC devices:

$$f_{MAX}^{(CP)} = \frac{1}{CP\text{-to-prop.delay} + CE\text{-to-setup} + CE\text{-to-CPHold}} = \frac{1}{42 + 12 + 2} \approx 18\text{MHz}$$

8. C_{PD} is used to determine the dynamic power consumption, per gate/package.

9. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

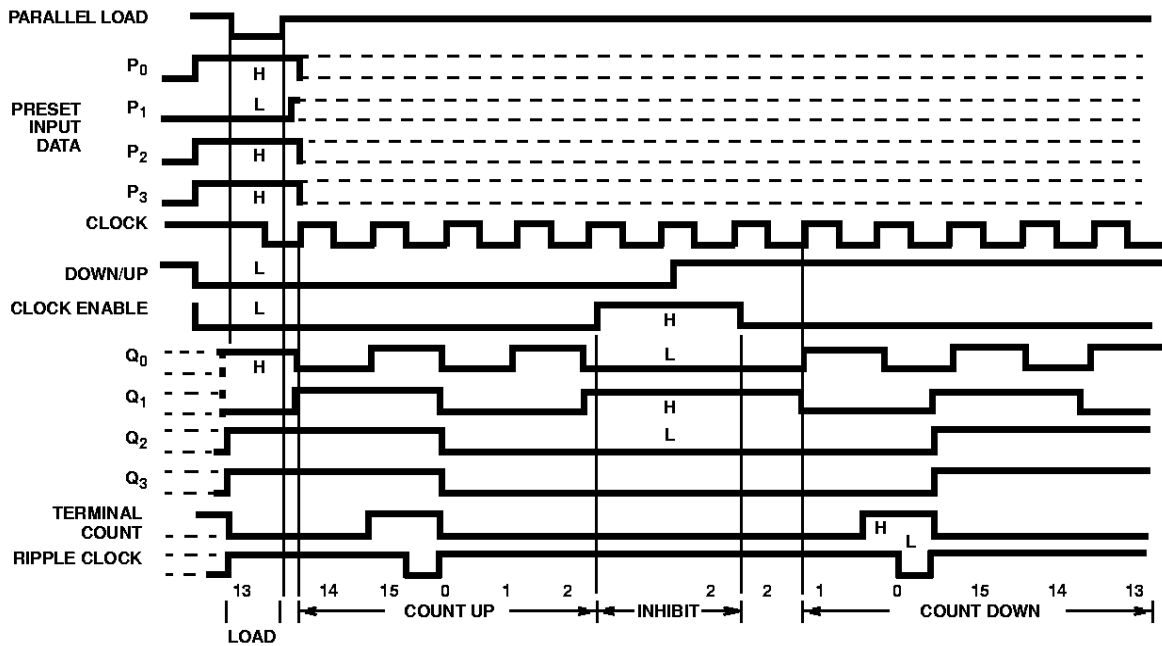
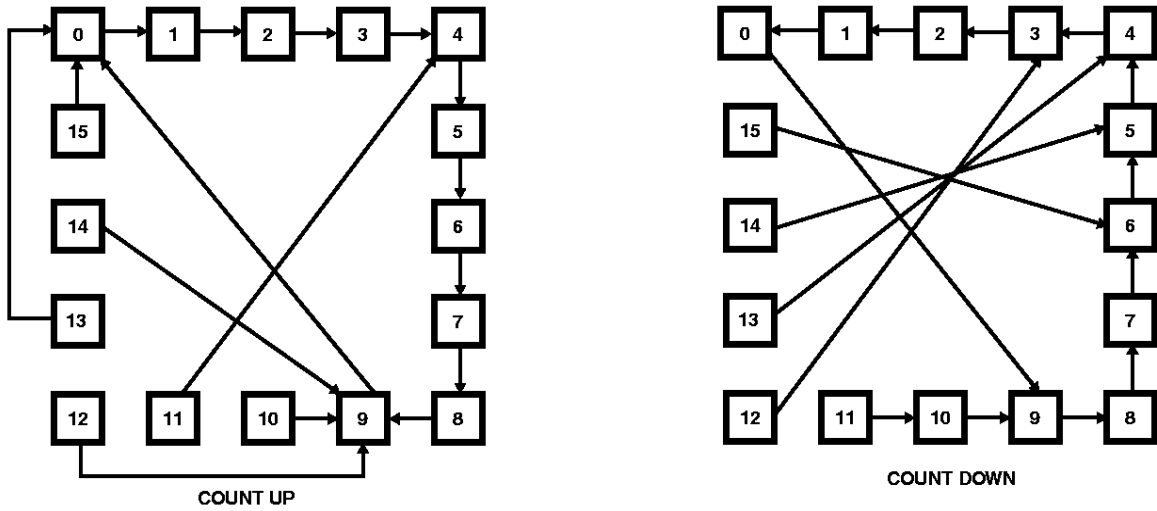


FIGURE 5. HC/HCT191 BINARY COUNTERS TYPICAL LOAD, COUNT AND INHIBIT SEQUENCES

Test Circuits and Waveforms (Continued)



NOTE: Illegal states in BCD counters corrected in one count.

NOTE: Illegal states in BCD counters corrected in one or two counts.

FIGURE 6. CD74HC191 STATE DIAGRAMS

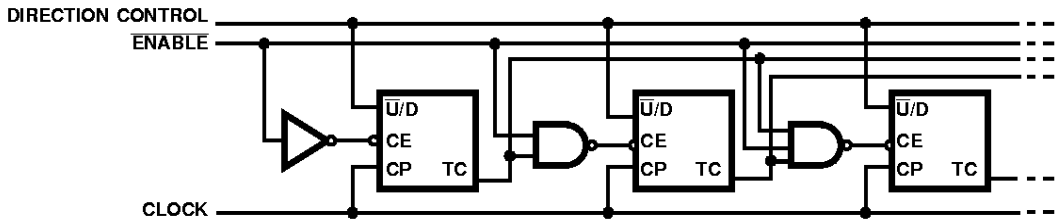


FIGURE 7. SYNCHRONOUS N-STAGE COUNTER WITH PARALLEL GATED TERMINAL COUNT

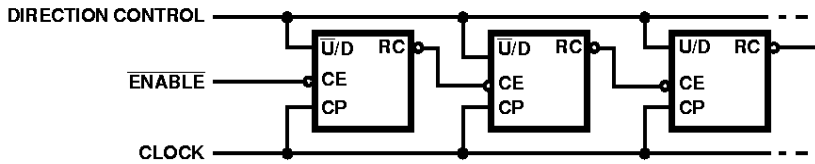


FIGURE 8. SYNCHRONOUS N-STAGE COUNTER USING RIPPLE CLOCK

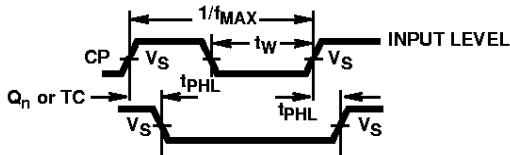


FIGURE 9.

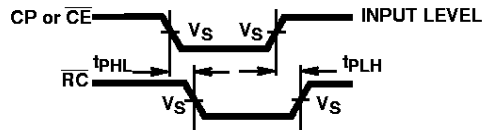


FIGURE 10.